

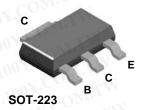
2N3906

MMBT3906

PZT3906







PNP General Purpose Amplifier

This device is designed for general purpose amplifier and switching applications at collector currents of 10 μ A to 100 mA.

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

Absolute Maximum Ratings*

T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	1100°V
V _{CBO}	Collector-Base Voltage	40	V.CO
V _{EBO}	Emitter-Base Voltage	5.0	V CO
Ic	Collector Current - Continuous	200	MA mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

 $^{{}^{\}textstyle \star} \text{These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.}$

NOTES

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
- 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

Thermal Characteristics T_A = 25°C unless otherwise noted

Symbol	Characteristic	WWW.Lo	Max		Units
	INW.100 COM.	2N3906	*MMBT3906	**PZT3906	WWW.
P_D	Total Device Dissipation	625	350	1,000	mW
R _{θJC}	Derate above 25°C Thermal Resistance, Junction to Case	5.0 83.3	2.8	8.0	mW/°C
R _{θJA}	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

^{**}Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

(continued)

	100 X.C	OM.TV
Electrical Characteristics	Floatrical Charact	orietics

T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHAI	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 10 \mu A, I_E = 0$	40	TW	V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5.0	TW	V
I _{BL}	Base Cutoff Current	$V_{CE} = 30 \text{ V}, V_{BE} = 3.0 \text{ V}$	-1 CO	50	nA
I _{CEX}	Collector Cutoff Current	$V_{CE} = 30 \text{ V}, V_{BE} = 3.0 \text{ V}$	00 2.	50	nA

	A A A A A A A A A A A A A A A A A A A		TIME		
h _{FE}	DC Current Gain *	$I_C = 0.1 \text{ mA}, V_{CE} = 1.0 \text{ V}$	60	COP	W
	1,100,100	$I_C = 1.0 \text{ mA}, V_{CE} = 1.0 \text{ V}$	80	Mor.	
		$I_C = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$	100	300	W
	1 IN . 100 r.	$I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$	60		
	NI TIWW.	$I_C = 100 \text{ mA}, V_{CE} = 1.0 \text{ V}$	30	V.Co	- 1777
CE(sat)	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$	TIN JU	0.25	V
ST CL	DAY WIN	$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$	N 4.	0.4	V
/ _{BE(sat)}	Base-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$	0.65	0.85	V
(()	Chr. and and and an	$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$	111	0.95	V

SMALL SIGNAL CHARACTERISTICS

f _T	Current Gain - Bandwidth Product	$I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	250	N.100	MHz
C _{obo}	Output Capacitance	$V_{CB} = 5.0 \text{ V}, I_{E} = 0,$ f = 100 kHz		4.5	pF
Cibo	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_{C} = 0,$ f = 100 kHz	W	10.0	pF
NF	Noise Figure	$I_C = 100 \mu A$, $V_{CE} = 5.0 V$, $R_S = 1.0 k \Omega$, $f = 10 Hz$ to 15.7 kHz		4.0	dB

SWITCHING CHARACTERISTICS

t _d	Delay Time	$V_{CC} = 3.0 \text{ V}, V_{BE} = 0.5 \text{ V},$	35	ns
t _r	Rise Time	I _C = 10 mA, I _{B1} = 1.0 mA	35	ns
ts	Storage Time	$V_{CC} = 3.0 \text{ V}, I_{C} = 10\text{mA}$	225	ns
t _f	Fall Time	I _{B1} = I _{B2} = 1.0 mA	75	ns

^{*}Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%

NOTE: All voltages (V) and currents (A) are negative polarity for PNP transistors.

Spice Model

PNP (Is=1.41f Xti=3 Eg=1.11 Vaf=18.7 Bf=180.7 Ne=1.5 Ise=0 Ikf=80m Xtb=1.5 Br=4.977 Nc=2 Isc=0 Ikr=0 Rc=2.5 Cjc=9.728p Mjc=.5776 Vjc=.75 Fc=.5 Cje=8.063p Mje=.3677 Vje=.75 Tr=33.42n Tf=179.3p ltf=.4 Vtf=4 Xtf=6 Rb=10)

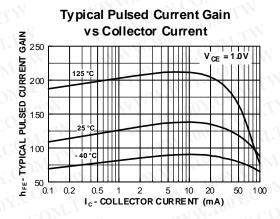
> 勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787

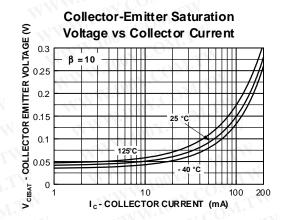
> > Http://www. 100y. com. tw

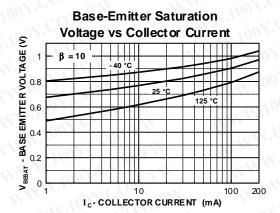
WWW.100Y.COM.

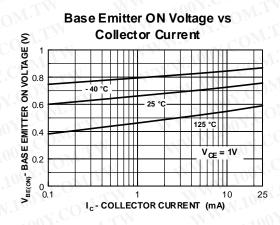
(continued)

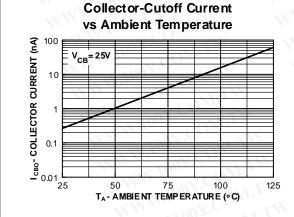
Typical Characteristics

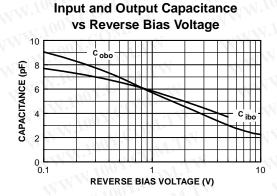










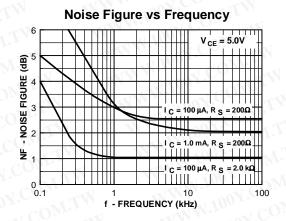


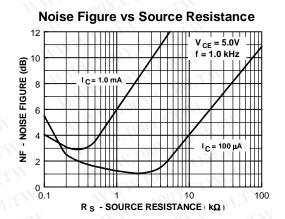
Common-Base Open Circuit

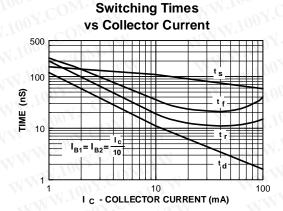
勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

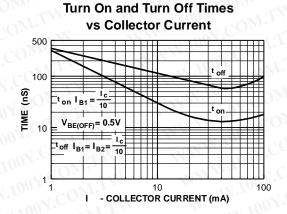
(continued)

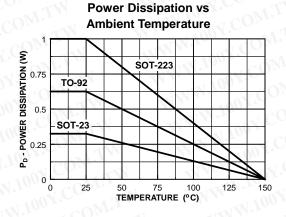
Typical Characteristics (continued)







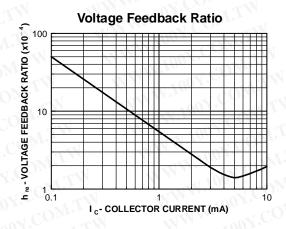


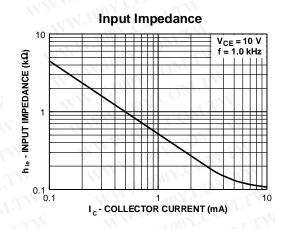


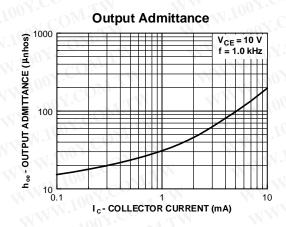
勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

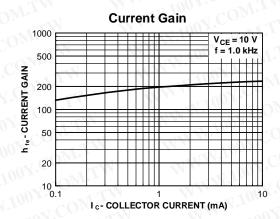
(continued)

Typical Characteristics (continued)









WWW.100Y.COM.

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

WWW.100Y.COM.

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

PowerTrench® SyncFET™ ACEx[™] FASTr™ QFET™ TinyLogic™ Bottomless™ GlobalOptoisolator™ QSTM UHC™ CoolFET™ **GTO™ VCX**TM CROSSVOLTTM QT Optoelectronics™ HiSeC™ DOME™ Quiet Series™ ISOPLANAR™ E2CMOSTM MICROWIRE™ SILENT SWITCHER® EnSigna™ **OPTOLOGIC™** SMART START™ FACT™ **OPTOPLANAR™** SuperSOT™-3 FACT Quiet Series™ PACMAN™ SuperSOT™-6 **POPTM** SuperSOT™-8 FAST®

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

Rev. G